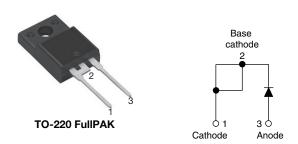


VS-30ETH06FP-F3, VS-30ETH06FP-N3

Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt®



PRIMARY CHARACTERISTICS				
Package	TO-220 FullPAK			
I _{F(AV)}	30 A			
V_{R}	600 V			
V _F at I _F	1.34 V			
t _{rr} (typ.)	23 ns			
T _J max.	175 °C			
Circuit configuration	Single			

FEATURES

- Reduced Q_{rr} and soft recovery
- 175 °C T_{.I} maximum
- For PFC CRM/CCM operation
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- UL E78996 approved

 Designed and qualified according JEDEC®-JESD 47

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





HALOGEN FREE

to

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V_{RRM}		600	V	
Average rectified forward current	I _{F(AV)}	T _C = 37 °C	30	Α	
Non-repetitive peak surge current	I _{FSM}	T _J = 25 °C	220	A	
Operating junction and storage temperatures	T _J , T _{Stg}		-65 to +175	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-	
Forward voltage V _F	I _F = 30 A	-	2.00	2.60	V	
	I _F = 30 A, T _J = 150 °C	-	1.34	1.75		
Reverse leakage current I _R	V _R = V _R rated	-	0.3	50		
	T _J = 150 °C, V _R = V _R rated	-	60	500	μA	
Junction capacitance	C _T	V _R = 600 V	-	33	-	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH

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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A, } dI_F/dt = 50 \text{ A/}\mu\text{s, } V_R = 30 \text{ V}$		-	28	35			
B	$I_F = 1 \text{ A, } dI_F/dt = 100 \text{ A/}\mu\text{s, } V_R = 30 \text{ V}$		-	23	30				
Reverse recovery time	t _{rr}	T _J = 25 °C		-	31	-	ns		
				T _J = 125 °C			-	77	-
Peak recovery current I _{RRM}	T _J = 25 °C	$I_F = 30 \text{ A}$	-	3.5	-	^			
	IRRM	T _J = 125 °C	$dI_F/dt = 200 A/\mu s$ $V_R = 200 V$	=	7.7	-	А		
Reverse recovery charge Q _{rr}		T _J = 25 °C		=	65	-	nC		
	T _J = 125 °C		-	345	-	110			

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		-65	-	175	°C
Thermal resistance, junction-to-case per leg	R _{thJC}		-	-	2.85	
Thermal resistance, junction-to-ambient per leg	R _{thJA}	Typical socket mount	-	-	70	°C/W
Thermal resistance, case-to-heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	
Weight			-	2	-	g
vveigni			-	0.07	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-220 FullPAK		30ETI	H06FP	

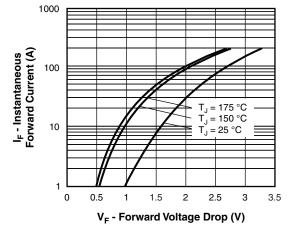


Fig. 1 - Typical Forward Voltage Drop Characteristics

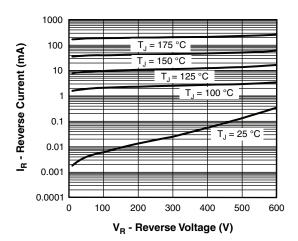


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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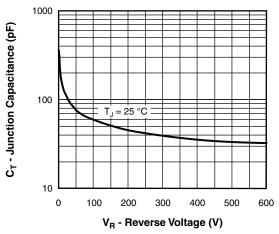


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

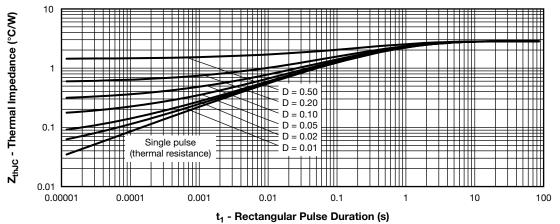


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

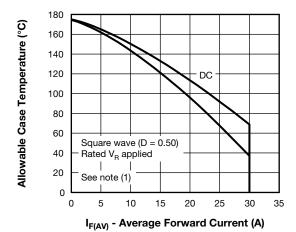


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

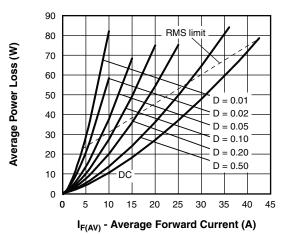


Fig. 6 - Forward Power Loss Characteristics

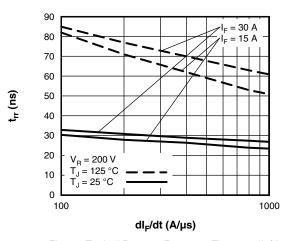


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

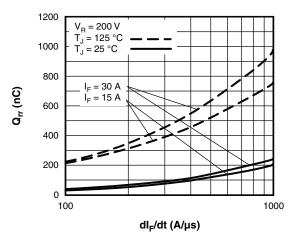
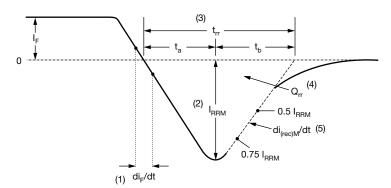


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $\begin{array}{l} \text{(1)} \ \ \text{Formula used:} \ T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \ \text{at } (I_{F(AV)}/D) \ \text{(see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \ \text{(1 - D)}; \ I_R \ \text{at } V_{R1} = \text{Rated } V_R \\ \end{array}$



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} x I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

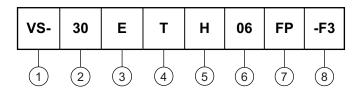
Fig. 9 - Reverse Recovery Waveform and Definitions

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Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (30 A)

3 - E = single

- T = TO-220

- H = hyperfast recovery

6 - Voltage rating (06 = 600 V)

7 - TO-220 FullPAK

8 - Environmental digit:

-F3 = RoHS-compliant and totally lead (Pb)-free

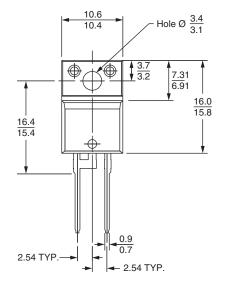
-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

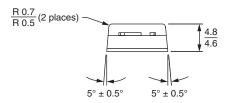
ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-30ETH06FP-F3	50	1000	Antistatic plastic tube		
VS-30ETH06FP-N3	50	1000	Antistatic plastic tube		

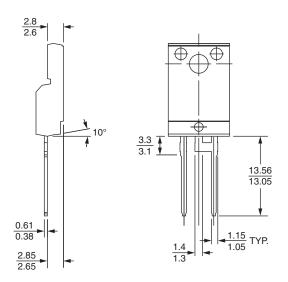
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95005</u>				
Part marking information	www.vishay.com/doc?95440			
SPICE model	www.vishay.com/doc?96440			

Vishay Semiconductors

DIMENSIONS in millimeters







Lead assignments

<u>Diodes</u> 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK



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